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74LV4051

8-channel analog multiplexer/demultiplexer Rev. 5 — 17 September 2014

Product data sheet

General description 1.

The 74LV4051 is an 8-channel analog multiplexer/demultiplexer with three digital select inputs (S0 to S2), an active-LOW enable input (E), eight independent inputs/outputs (Y0 to Y7) and a common input/output (Z). It is a low-voltage Si-gate CMOS device that is pin and function compatible with 74HC4051 and 74HCT4051. With E LOW, one of the eight switches is selected (low impedance ON-state) by S0 to S2. With E HIGH, all switches are in the high-impedance OFF-state, independent of S0 to S2.

 V_{CC} and GND are the supply voltage pins for the digital control inputs (S0 to S2, and \overline{E}). The V_{CC} to GND ranges are 1.0 V to 6.0 V. The analog inputs/outputs (Y0 to Y7, and Z) can swing between V_{CC} as a positive limit and V_{EE} as a negative limit. $V_{CC} - V_{EE}$ may not exceed 6.0 V. For operation as a digital multiplexer/demultiplexer, VEE is connected to GND (typically ground).

Features and benefits 2.

- Optimized for low-voltage applications: 1.0 V to 6.0 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Low ON resistance:
 - ♦ 145 Ω (typical) at $V_{CC} V_{EE} = 2.0 \text{ V}$
 - 80 Ω (typical) at $V_{CC} V_{EE} = 3.0 \text{ V}$
 - 60 Ω (typical) at $V_{CC} V_{EE} = 4.5 \text{ V}$
- Logic level translation:
 - ◆ To enable 3 V logic to communicate with ±3 V analog signals
- Typical 'break before make' built in
- ESD protection:
 - HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



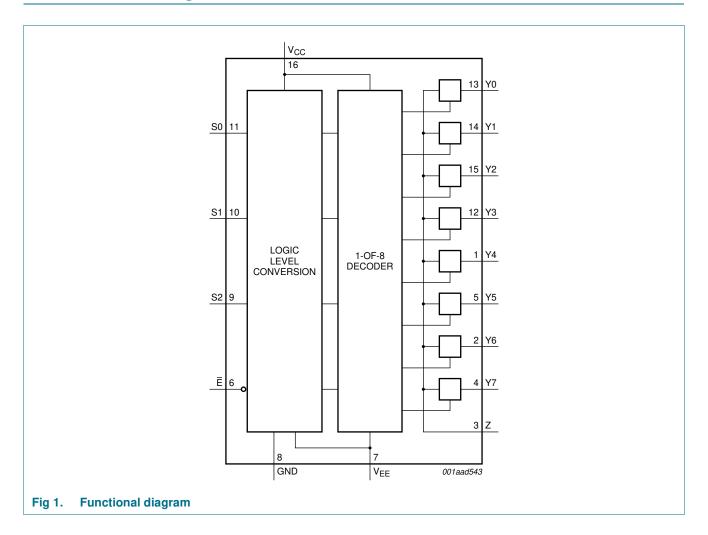
8-channel analog multiplexer/demultiplexer

3. Ordering information

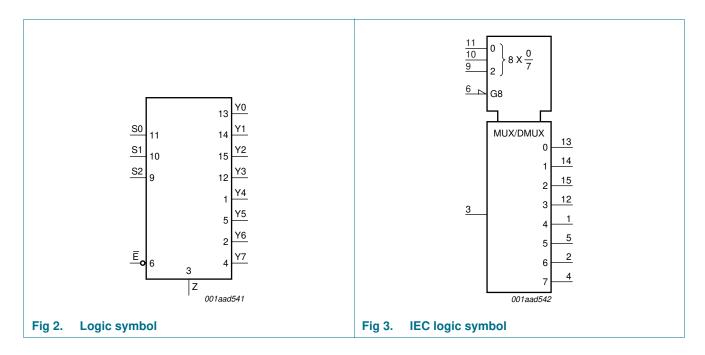
Table 1. Ordering information

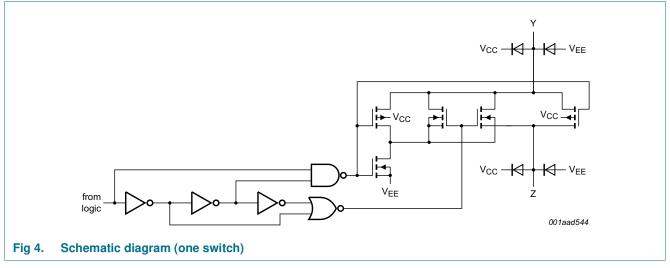
Type number	Package								
	Temperature range	Name	Description	Version					
74LV4051N	-40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4					
74LV4051D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					
74LV4051DB	-40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1					
74LV4051PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1					
74LV4051BQ	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm	SOT763-1					

4. Functional diagram



8-channel analog multiplexer/demultiplexer

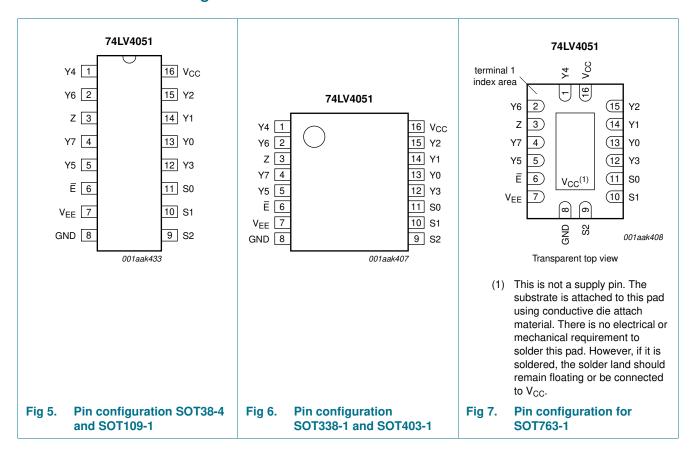




8-channel analog multiplexer/demultiplexer

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description			
Ē	6	enable input (active LOW)			
V _{EE}	7	supply voltage			
GND 8		ground supply voltage			
S0, S1, S2	11, 10, 9	select input			
Y0, Y1, Y2, Y3, Y4, Y5, Y6, Y7	13, 14, 15, 12, 1, 5, 2, 4	independent input or output			
Z	3	common output or input			
V _{CC}	16	supply voltage			

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6. Functional description

6.1 Function table

Table 3. Function table[1]

Input				Channel ON	
E	S2	S1	S0		
L	L	L	L	Y0 to Z	
L	L	L	Н	Y1 to Z	
L	L	Н	L	Y2 to Z	
L	L	Н	Н	Y3 to Z	
L	Н	L	L	Y4 to Z	
L	Н	L	Н	Y5 to Z	
L	Н	Н	L	Y6 to Z	
L	Н	Н	Н	Y7 to Z	
Н	X	X	X	switches off	

^[1] H = HIGH voltage level;

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V_{SS} = 0 V (ground).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage		[1]	-0.5	+7.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	[2]	-	±20	mA
I _{SK}	switch clamping current	V_{SW} < -0.5 V or V_{SW} > V_{CC} + 0.5 V	[2]	-	±20	mA
I _{SW}	switch current	$V_{SW} > -0.5 \text{ V or } V_{SW} < V_{CC} + 0.5 \text{ V};$ source or sink current	[2]	-	±25	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[3]			
		DIP16 package		-	750	mW
		SO16 package		-	500	mW
		TSSOP16 package		-	500	mW
		DHVQFN16 package		-	500	mW

^[1] To avoid drawing V_{CC} current out of terminal Z, when switch current flows into terminals Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminals Yn, and in this case there is no limit for the voltage drop across the switch, but the voltages at Yn and Z may not exceed V_{CC} or V_{EE}.

For SO16 packages: above 70 $^{\circ}\text{C}$ the value of P_{tot} derates linearly with 8 mW/K.

For SSOP16 and TSSOP16 packages: above 60 $^{\circ}$ C the value of P_{tot} derates linearly with 5.5 mW/K.

For DHVQFN16 packages: above 60 °C the value of Ptot derates linearly with 4.5 mW/K.

L = LOW voltage level;

X = don't care.

^[2] The minimum input voltage rating may be exceeded if the input current rating is observed.

^[3] For DIP16 packages: above 70 °C the value of Ptot derates linearly with 12 mW/K.

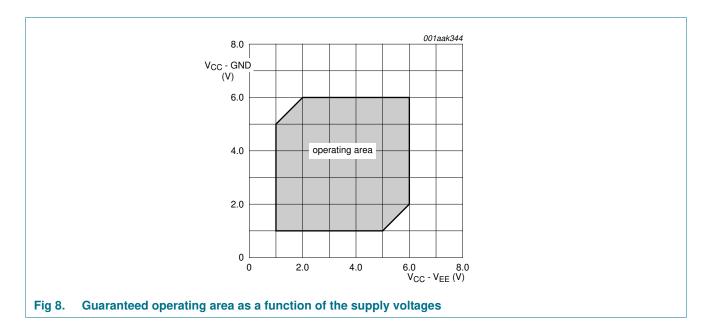
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8. Recommended operating conditions

Table 5. Recommended operating conditions[1]

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage	see Figure 8	1	3.3	6	V
VI	input voltage		0	-	V _{CC}	V
V_{SW}	switch voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature	in free air	-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	V _{CC} = 1.0 V to 2.0 V	-	-	500	ns/V
		V _{CC} = 2.0 V to 2.7 V	-	-	200	ns/V
		V _{CC} = 2.7 V to 3.6 V	-	-	100	ns/V

^[1] The static characteristics are guaranteed from V_{CC} = 1.2 V to 6.0 V, but LV devices are guaranteed to function down to V_{CC} = 1.0 V (with input levels GND or V_{CC}).



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9. Static characteristics

Table 6. Static characteristics

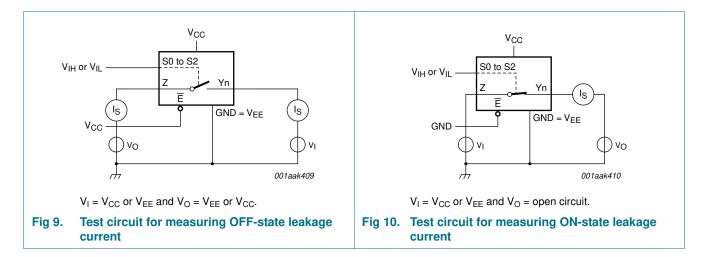
At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
V_{IH}	HIGH-level input voltage	V _{CC} = 1.2 V	0.9	-	-	0.9	-	V
		V _{CC} = 2.0 V	1.4	-	-	1.4	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.0	-	-	2.0	-	V
		V _{CC} = 4.5 V	3.15	-	-	3.15	-	V
		$V_{CC} = 6.0 \text{ V}$	4.20	-	-	4.20	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 1.2 V	-	-	0.3	-	0.3	V
		$V_{CC} = 2.0 \text{ V}$	-	-	0.6	-	0.6	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.8	-	0.8	V
		V _{CC} = 4.5 V	-	-	1.35	-	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	-	1.80	-	1.80	V
input leakage current	input leakage current	$V_I = V_{CC}$ or GND						
		$V_{CC} = 3.6 \text{ V}$	-	-	1.0	-	1.0	μΑ
		$V_{CC} = 6.0 \text{ V}$	-	-	2.0	-	2.0	μΑ
I _{S(OFF)}	OFF-state leakage current	V _I = V _{IH} or V _{IL} ; see <u>Figure 9</u>						
		$V_{CC} = 3.6 \text{ V}$	-	-	1.0	-	1.0	μΑ
		$V_{CC} = 6.0 \text{ V}$	-	-	2.0	-	2.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_I = V_{IH}$ or V_{IL} ; see Figure 10						
		V _{CC} = 3.6 V	-	-	1.0	-	1.0	μА
		$V_{CC} = 6.0 \text{ V}$	-	-	2.0	-	1.0 2.0 1.0 2.0 40 80 850	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A						
		$V_{CC} = 3.6 \text{ V}$	-	-	20	-	40	μΑ
		$V_{CC} = 6.0 \text{ V}$	-	-	40	-	80	μА
Δl _{CC}	additional supply current	per input; $V_I = V_{CC} - 0.6 \text{ V}$; $V_{CC} = 2.7 \text{ V}$ to 3.6 V	-	-	500	-	850	μА
Cı	input capacitance		-	3.5	-	-	-	рF
C _{sw}	switch capacitance	independent pins Yn	-	5	-	-	-	рF
		common pin Z	-	25	-	-	-	pF

^[1] Typical values are measured at T_{amb} = 25 °C.

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9.1 Test circuits



9.2 ON resistance

Table 7. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see <u>Figure 11</u> and <u>Figure 12</u>.

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
R _{ON(peak)}	ON resistance (peak)	$V_I = 0 V \text{ to } V_{CC} - V_{EE}$							
		$V_{CC} = 1.2 \text{ V}; I_{SW} = 100 \mu\text{A}$	[2]	-	-	-	-	-	Ω
		$V_{CC} = 2.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	145	325	-	375	Ω
		$V_{CC} = 2.7 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	90	200	-	235	Ω
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $I_{SW} = 1000 \mu\text{A}$		-	80	180	-	210	Ω
		$V_{CC} = 4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	60	135	-	160	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	55	125	-	145	Ω
ΔR_{ON}	ON resistance mismatch	$V_I = 0 V \text{ to } V_{CC} - V_{EE}$							
	between channels	$V_{CC} = 1.2 \text{ V}; I_{SW} = 100 \mu\text{A}$	[2]	-	-	-	-	-	Ω
		$V_{CC} = 2.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	5	-	-	-	Ω
		$V_{CC} = 2.7 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	4	-	-	-	Ω
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $I_{SW} = 1000 \mu\text{A}$		-	4	-	-	-	Ω
		$V_{CC} = 4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	3	-	-	-	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	2	-	-	-	Ω

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Table 7. ON resistance ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see <u>Figure 11</u> and Figure 12.

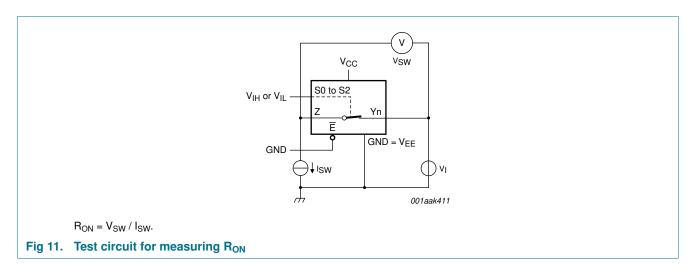
Symbol	Parameter	Conditions		-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
R _{ON(rail)}	ON resistance (rail)	V _I = GND							
		$V_{CC} = 1.2 \text{ V}; I_{SW} = 100 \mu\text{A}$	[2]	-	225	-	-	-	Ω
		$V_{CC} = 2.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	110	235	-	270	Ω
		$V_{CC} = 2.7 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	70	145	-	165	Ω
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $I_{SW} = 1000 \mu\text{A}$		-	60	130	-	150	Ω
		$V_{CC} = 4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	45	100	-	115	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	40	85	-	100	Ω
R _{ON(rail)}	ON resistance (rail)	$V_I = V_{CC} - V_{EE}$							
		$V_{CC} = 1.2 \text{ V}; I_{SW} = 100 \mu\text{A}$	[2]	-	250	-	-	-	Ω
		$V_{CC} = 2.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	120	320	-	370	Ω
		$V_{CC} = 2.7 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	75	195	-	225	Ω
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $I_{SW} = 1000 \mu\text{A}$		-	70	175	-	205	Ω
		$V_{CC} = 4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	50	130	-	150	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	45	120	-	135	Ω

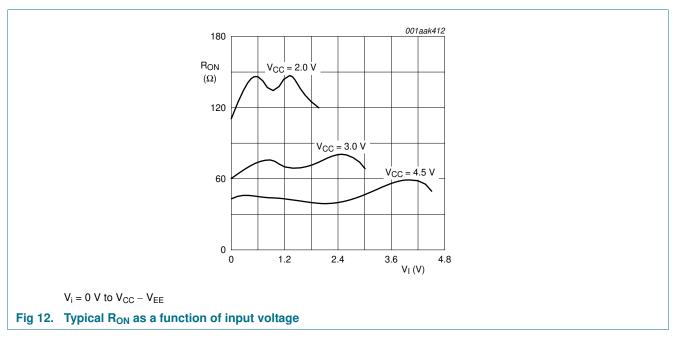
^[1] Typical values are measured at T_{amb} = 25 °C.

^[2] When supply voltages $(V_{CC} - V_{EE})$ near 1.2 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 1.2 V, it is recommended to use these devices only for transmitting digital signals.

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9.3 On resistance waveform and test circuit





8-channel analog multiplexer/demultiplexer

10. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 15.

Symbol	Parameter	Conditions		-40	°C to +85	5 °C	–40 °C t	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	Yn to Z, Z to Yn; see Figure 13	[2]						
		V _{CC} = 1.2 V		-	25	-	-	-	ns
		V _{CC} = 2.0 V		-	9	17	-	20	ns
		V _{CC} = 2.7 V		-	6	13	-	15	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	5	10	-	12	ns
		V _{CC} = 4.5 V		-	4	9	-	10	ns
		V _{CC} = 6.0 V		-	3	8	-	8	ns
t _{en}	enable time	E to Yn, Z; see Figure 14	[2]						
		V _{CC} = 1.2 V		-	145	-	-	-	ns
		V _{CC} = 2.0 V		-	49	94	-	112	ns
		V _{CC} = 2.7 V		-	36	69	-	83	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$	[3]	-	23	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	28	55	-	66	ns
		V _{CC} = 4.5 V		-	25	47	-	56	ns
		V _{CC} = 6.0 V		-	19	38	-	43	ns
		Sn to Yn; see Figure 14	[2]						
		V _{CC} = 1.2 V		-	140	-	-	-	ns
		V _{CC} = 2.0 V		-	48	90	-	107	ns
		V _{CC} = 2.7 V		-	35	66	-	79	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$	[3]	-	22	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	27	53	-	63	ns
		V _{CC} = 4.5 V		-	24	45	-	54	ns
		V _{CC} = 6.0 V		-	18	34	-	41	ns

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 Table 8.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 15.

Symbol	Parameter	Conditions		-40	°C to +85	o°C	–40 °C t	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t _{dis}	disable time	E to Yn, Z; see Figure 14	[2]						
		V _{CC} = 1.2 V		-	145	-	-	-	ns
		V _{CC} = 2.0 V		-	51	93	-	110	ns
		V _{CC} = 2.7 V		-	38	69	-	82	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$	[3]	-	25	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	30	56	-	66	ns
		V _{CC} = 4.5 V		-	29	48	-	56	ns
		V _{CC} = 6.0 V		-	21	37	-	44	ns
		Sn to Yn; see Figure 14	[2]						
		V _{CC} = 1.2 V		-	115	-	-	-	ns
		V _{CC} = 2.0 V		-	41	73	-	90	ns
		V _{CC} = 2.7 V		-	31	54	-	67	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$	[3]	-	20	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	24	44	-	54	ns
		V _{CC} = 4.5 V		-	22	37	-	46	ns
		V _{CC} = 6.0 V		-	17	29	-	36	ns
C _{PD}	power dissipation capacitance	C_L = 50 pF; f_i = 1 MHz; V_I = GND to V_{CC}	[4]	-	25	-	-	-	pF

- [1] All typical values are measured at T_{amb} = 25 °C.
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} .
 - t_{en} is the same as t_{PZL} and $t_{\text{PZH}}.$
 - t_{dis} is the same as t_{PLZ} and t_{PHZ} .
- [3] Typical values are measured at nominal supply voltage ($V_{CC} = 3.3 \text{ V}$).
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma((C_L + C_{SW}) \times V_{CC}^2 \times f_o) \text{ where:}$$

 f_i = input frequency in MHz, f_o = output frequency in MHz

 C_L = output load capacitance in pF

C_{SW} = maximum switch capacitance in pF;

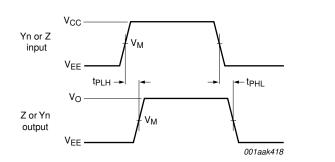
 V_{CC} = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$ = sum of the outputs.

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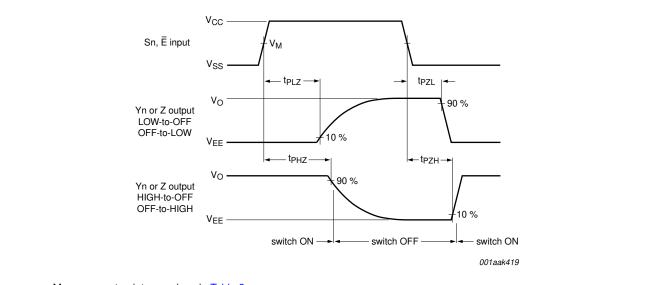
10.1 Waveforms



Measurement points are given in Table 9.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 13. Propagation delay input (An) to output (Yn)



Measurement points are given in Table 9.

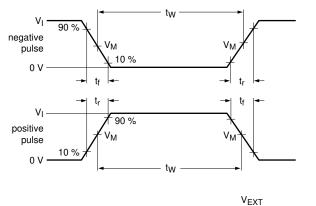
 $\ensuremath{V_{OL}}$ and $\ensuremath{V_{OH}}$ are typical voltage output levels that occur with the output load.

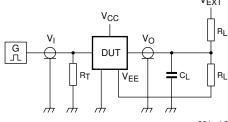
Fig 14. Enable and disable times

Table 9. Measurement points

Supply voltage	Input	Output							
V _{CC}	V _M	V _M	V _X	V _Y					
< 2.7 V	0.5V _{CC}	0.5V _{CC}	$V_{OL} + 0.1V_{CC}$	V _{OH} - 0.1V _{CC}					
2.7 V to 3.6 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} – 0.3 V					
> 3.6 V	0.5V _{CC}	0.5V _{CC}	$V_{OL} + 0.1V_{CC}$	V _{OH} – 0.1V _{CC}					

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Test data is given in Table 10.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 15. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input		Load		V _{EXT}			
V _{CC}	VI	t _r , t _f	C _L	R _L	t _{PHL} , t _{PLH}	t_{PZH} , t_{PHZ}	t _{PZL} , t _{PLZ}	
< 2.7 V	V _{CC}	≤ 6 ns	50 pF	1 kΩ	open	V _{EE}	2V _{CC}	
2.7 V to 3.6 V	2.7 V	≤ 6 ns	15 pF, 50 pF	1 kΩ	open	V _{EE}	2V _{CC}	
> 3.6 V	V _{CC}	≤ 6 ns	50 pF	1 kΩ	open	V _{EE}	2V _{CC}	

8-channel analog multiplexer/demultiplexer

10.2 Additional dynamic parameters

Table 11. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); V_I = GND or V_{CC} (unless otherwise specified); t_r = $t_f \le 6.0$ ns; T_{amb} = 25 °C.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
THD	total harmonic	$f_i = 1 \text{ kHz}$; $C_L = 50 \text{ pF}$; $R_L = 10 \text{ k}\Omega$; see Figure 20					
	distortion	V _{CC} = 3.0 V; V _I = 2.75 V (p-p)		-	0.8	-	%
		V _{CC} = 6.0 V; V _I = 5.5 V (p-p)		-	0.4	-	%
		f_i = 10 kHz; C_L = 50 pF; R_L = 10 k Ω ; see Figure 20					
		V _{CC} = 3.0 V; V _I = 2.75 V (p-p)		-	2.4	-	%
		V _{CC} = 6.0 V; V _I = 5.5 V (p-p)		-	1.2	-	%
f _(-3dB)	-3 dB frequency	$C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 16	[1]				
	response	V _{CC} = 3.0 V		-	180	-	MHz
		V _{CC} = 6.0 V		-	200	-	MHz
α_{iso}	isolation (OFF-state)	f_i = 1 MHz; C_L = 50 pF; R_L = 600 Ω ; see Figure 18	[2]				
		V _{CC} = 3.0 V		-	-50	-	dB
		V _{CC} = 6.0 V		-	-50	-	dB
V _{ct}	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 600 \Omega$; see Figure 21	[2]				
		V _{CC} = 3.0 V		-	0.11	-	V
		V _{CC} = 6.0 V		-	0.12	-	V
Xtalk	crosstalk	between switches; f_i = 1 MHz; C_L = 50 pF; R_L = 600 Ω ; see Figure 22					
		V _{CC} = 3.0 V		-	-60	-	dB
		$V_{CC} = 6.0 \text{ V}$		-	-60	-	dB

^[1] Adjust f_i voltage to obtain 0 dBm level at output for 1 MHz (0 dBm = 1 mW into 50 Ω).

^[2] Adjust f_i voltage to obtain 0 dBm level at output for 1 MHz (0 dBm = 1 mW into 600 Ω).

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10.2.1 Test circuits

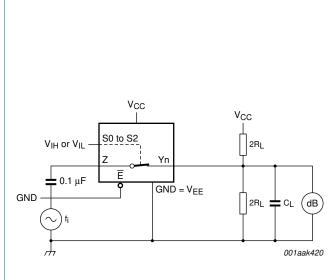
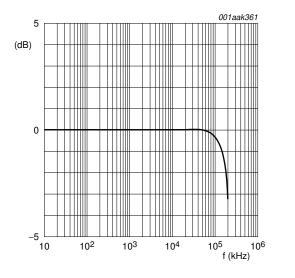


Fig 16. Test circuit for measuring frequency response



 V_{CC} = 3.0 V; GND = 0 V; V_{EE} = -3.0 V; R_L = 50 $\Omega;$ R_{SOURCE} = 1 $k\Omega.$

Fig 17. Typical frequency response

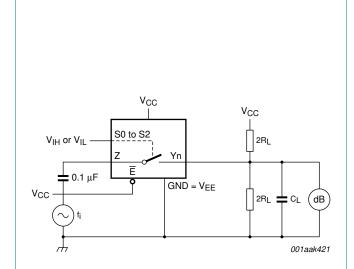
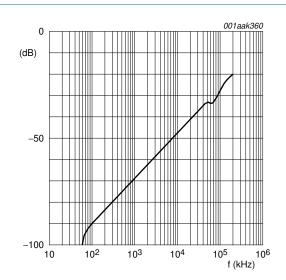


Fig 18. Test circuit for measuring isolation (OFF-state)



 V_{CC} = 3.0 V; GND = 0 V; V_{EE} = -3.0 V; R_L = 50 Ω ; R_{SOUBCE} = 1 k Ω .

Fig 19. Typical isolation (OFF-state) as function of frequency

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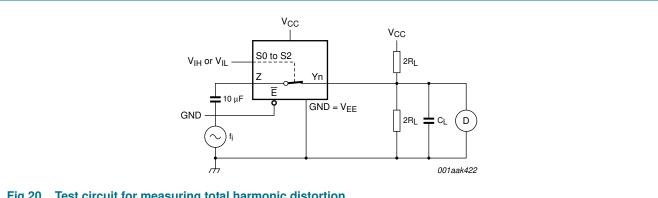
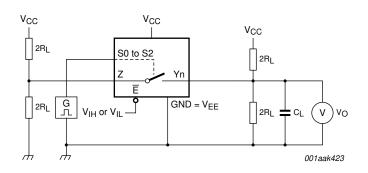
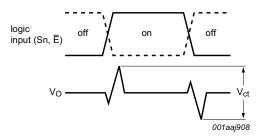


Fig 20. Test circuit for measuring total harmonic distortion



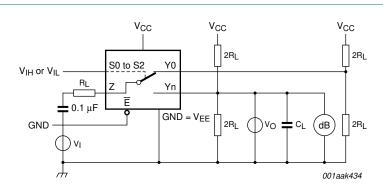
a. Test circuit



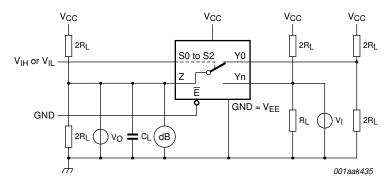
b. Input and output pulse definitions V_I may be connected to Sn or \overline{E} .

Fig 21. Test circuit for measuring crosstalk voltage between digital inputs and switch

8-channel analog multiplexer/demultiplexer



a. Switch closed condition



b. Switch open condition

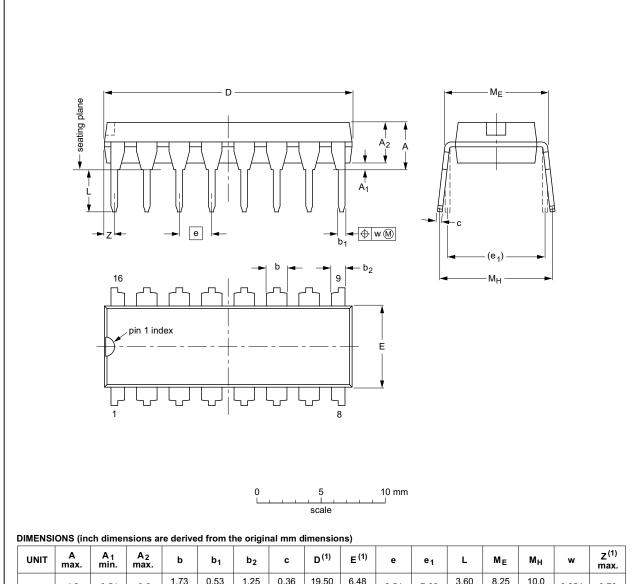
Fig 22. Test circuit for measuring crosstalk between switches

8-channel analog multiplexer/demultiplexer

11. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT38-4					95-01-14 03-02-13

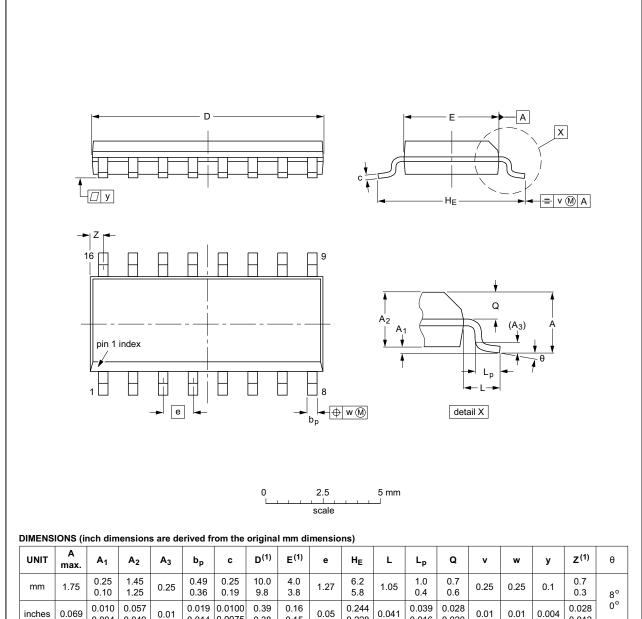
Fig 23. Package outline SOT38-4 (DIP16)

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8-channel analog multiplexer/demultiplexer

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



inches

Note 1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

0.014 0.0075

0.38

0.15

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012			99-12-27 03-02-19

0.228

0.016

0.020

Fig 24. Package outline SOT109-1 (SO16)

0.004

0.049

74LV4051

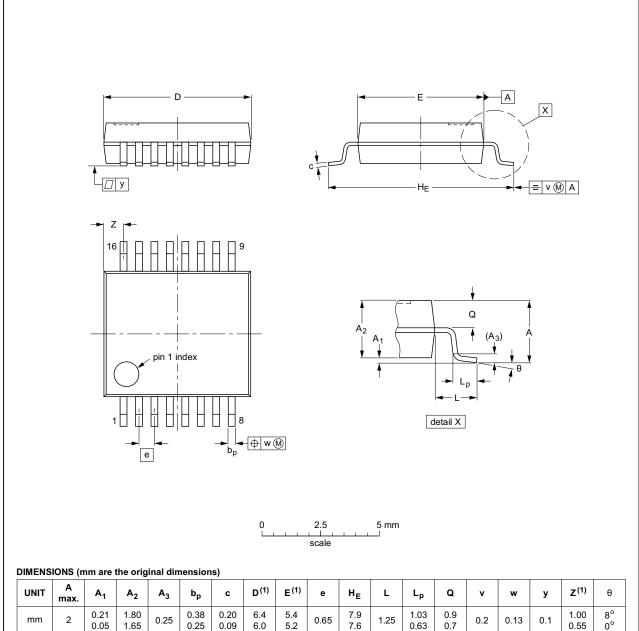
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8-channel analog multiplexer/demultiplexer

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	C	D ⁽¹⁾	E ⁽¹⁾	e	HE	L	Lp	Q	٧	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT338-1		MO-150			99-12-27 03-02-19

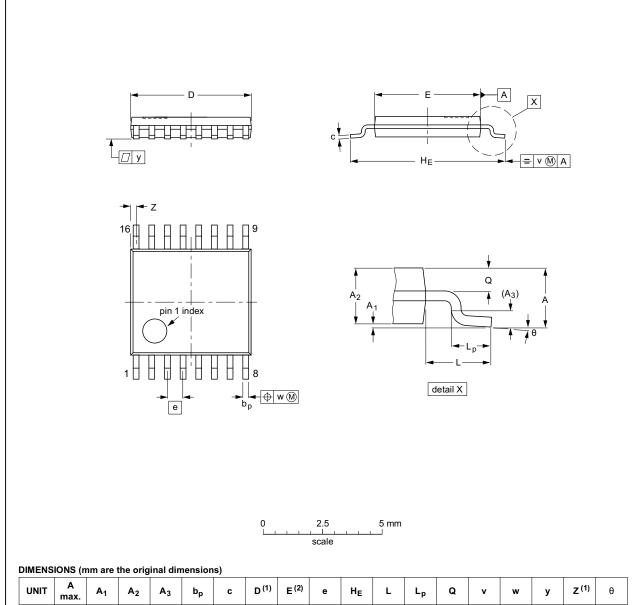
Fig 25. Package outline SOT338-1 (SSOP16)

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8-channel analog multiplexer/demultiplexer

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	C	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT403-1		MO-153			99-12-27 03-02-18

Fig 26. Package outline SOT403-1 (TSSOP16)

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8-channel analog multiplexer/demultiplexer

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

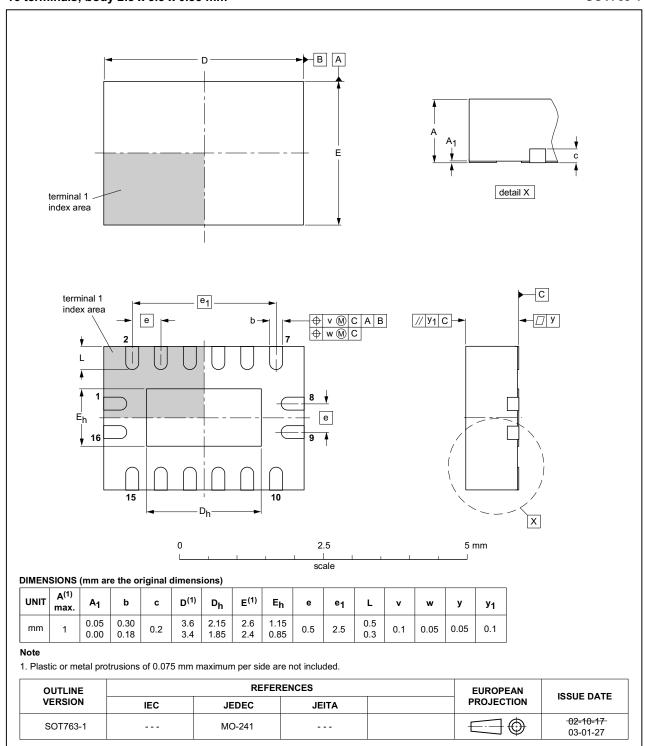


Fig 27. Package outline SOT763-1 (DHVQFN16)

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8-channel analog multiplexer/demultiplexer

12. Abbreviations

Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LV4051 v.5	20140917	Product data sheet	-	74LV4051 v.4
Modifications:	• Figure 7: F	igure note added for DHVC	FN16 package	
74LV4051 v.4	20090810	Product data sheet	-	74LV4051 v.3
Modifications:		of this data sheet has been miconductors.	n redesigned to comp	ply with the new identity guidelines
	 Legal texts 	have been adapted to the	new company name	where appropriate.
	 Added type 	e number 74LV4051BQ (DF	IVQFN16 package)	
74LV4051 v.3	19960623	Product specification	-	74LV4051 v.2
74LV4051 v.2	19970715	Product specification	-	74LV4051 v.1

8-channel analog multiplexer/demultiplexer

14. Legal information

14.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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